

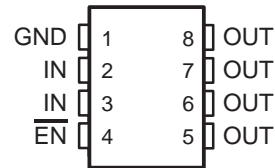


# THE DATASHEET OF TPS2012DRG4

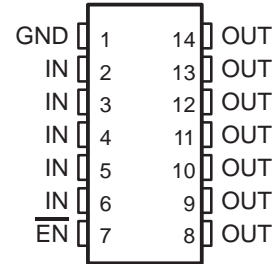


- **95-mΩ Max (5.5-V Input) High-Side MOSFET Switch With Logic Compatible Enable Input**
- **Short-Circuit and Thermal Protection**
- **Typical Short-Circuit Current Limits:**  
0.4 A, TPS2010; 1.2 A, TPS2011;  
2 A, TPS2012; 2.6 A, TPS2013
- **Electrostatic-Discharge Protection, 12-kV Output, 6-kV All Other Terminals**
- **Controlled Rise and Fall Times to Limit Current Surges and Minimize EMI**
- **SOIC-8 Package Pin Compatible With the Popular Littlefoot™ Series When GND Is Connected**
- **2.7-V to 5.5-V Operating Range**
- **10-μA Maximum Standby Current**
- **Surface-Mount SOIC-8 and TSSOP-14 Packages**
- **–40°C to 125°C Operating Junction Temperature Range**

**D PACKAGE  
(TOP VIEW)**



**PW PACKAGE  
(TOP VIEW)**



## description

The TPS201x family of power-distribution switches is intended for applications where heavy capacitive loads and short circuits are likely to be encountered. The high-side switch is a 95-mΩ N-channel MOSFET. Gate drive is provided by an internal driver and charge pump designed to control the power switch rise times and fall times to minimize current surges during switching. The charge pump operates at 100 kHz, requires no external components, and allows operation from supplies as low as 2.7 V. When the output load exceeds the current-limit threshold or a short circuit is present, the TPS201x limits the output current to a safe level by switching into a constant-current mode. Continuous heavy overloads and short circuits increase power dissipation in the switch and cause the junction temperature to rise. If the junction temperature reaches approximately 180°C, a thermal protection circuit shuts the switch off to prevent damage. Recovery from thermal shutdown is automatic once the device has cooled sufficiently.

The members of the TPS201x family differ only in short-circuit current threshold. The TPS2010 is designed to limit at 0.4-A load; the other members of the family limit at 1.2 A, 2 A, and 2.6 A (see the available options table). The TPS201x family is available in 8-pin small-outline integrated circuit (SOIC) and 14-pin thin shink small-outline (TSSOP) packages and operates over a junction temperature range of –40°C to 125°C. Versions in the 8-pin SOIC package are drop-in replacements for Siliconix's Littlefoot™ power PMOS switches, except that GND must be connected.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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## detailed description (continued)

### driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage. The rise and fall times are typically in the 2-ms to 4-ms range instead of the microsecond or nanosecond range for a standard FET.

### enable ( $\overline{\text{EN}}$ )

A logic high on the  $\overline{\text{EN}}$  input turns off the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current to less than 10  $\mu\text{A}$ . A logic zero input restores bias to the drive and control circuits and turns the power on. The enable input is compatible with both TTL and CMOS logic levels.

### current sense

A sense FET monitors the current supplied to the load. The sense FET is a much more efficient way to measure current than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its linear region, which switches the output into a constant current mode and simply holds the current constant while varying the voltage on the load.

### thermal sense

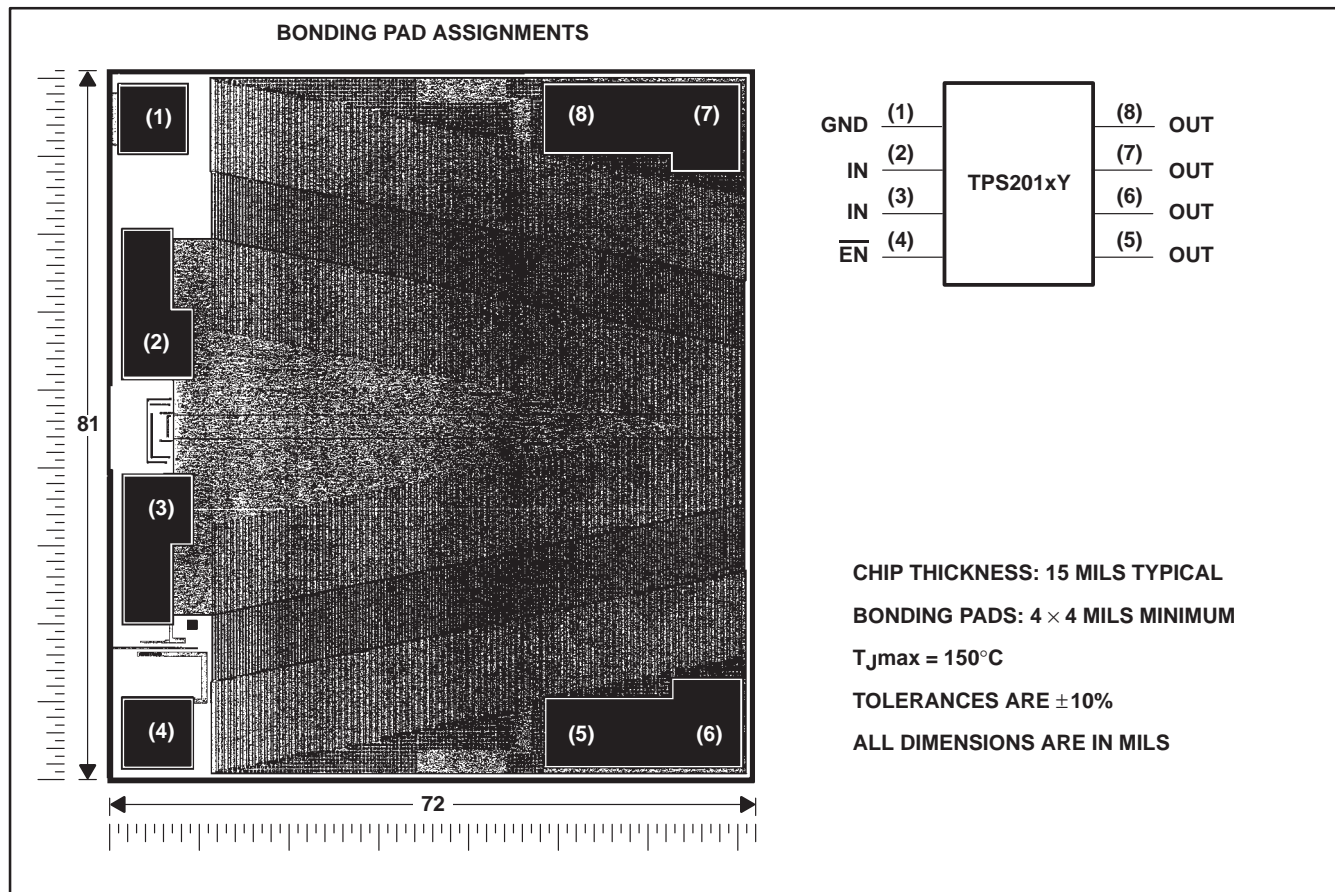
An internal thermal-sense circuit shuts the power switch off when the junction temperature rises to approximately 180°C. Hysteresis is built into the thermal sense, and after the device has cooled approximately 20 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed.

## TPS201xY chip information

This chip, when properly assembled, displays characteristics similar to the TPS201xC. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chip may be mounted with conductive epoxy or a gold-silicon preform.

# TPS2010, TPS2011, TPS2012, TPS2013 POWER-DISTRIBUTION

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range, $V_{I(IN)}$ (see Note 1)	−0.3 V to 7 V
Output voltage range, $V_O$ (see Note 1)	−0.3 V to $V_{I(IN)} + 0.3$ V
Input voltage range, $V_I$ at $\overline{\text{EN}}$	−0.3 V to 7 V
Continuous output current, $I_O$	internally limited
Continuous total power dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, $T_J$	−40°C to 125°C
Storage temperature range, $T_{stg}$	−65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	145 mW
PW	700 mW	5.6 mW/°C	448 mW	140 mW



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**recommended operating conditions**

		MIN	MAX	UNIT
Input voltage, $V_{I(IN)}$		2.7	5.5	V
Input voltage, $V_I$ at $\overline{EN}$		0	5.5	V
Continuous output current, $I_O$	TPS2010	0	0.2	A
	TPS2011	0	0.6	
	TPS2012	0	1	
	TPS2013	0	1.5	
Operating virtual junction temperature, $T_J$		-40	125	°C

**electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5$  V,  $I_O =$  rated current,  $\overline{EN} = 0$  V (unless otherwise noted)**

**power switch**

PARAMETER	TEST CONDITIONS†	TPS2010, TPS2011 TPS2012, TPS2013			UNIT
		MIN	TYP	MAX	
On-state resistance	$V_{I(IN)} = 5.5$ V, $T_J = 25^\circ\text{C}$		75	95	mΩ
	$V_{I(IN)} = 4.5$ V, $T_J = 25^\circ\text{C}$		80	110	
	$V_{I(IN)} = 3$ V, $T_J = 25^\circ\text{C}$		120	175	
	$V_{I(IN)} = 2.7$ V, $T_J = 25^\circ\text{C}$		140	215	
Output leakage current	$\overline{EN} = V_{I(IN)}$ , $T_J = 25^\circ\text{C}$		0.001	1	μA
	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$			10	
$t_r$ Output rise time	$V_{I(IN)} = 5.5$ V, $T_J = 25^\circ\text{C}$ , $C_L = 1$ μF		4		ms
	$V_{I(IN)} = 2.7$ V, $T_J = 25^\circ\text{C}$ , $C_L = 1$ μF		3.8		
$t_f$ Output fall time	$V_{I(IN)} = 5.5$ V, $T_J = 25^\circ\text{C}$ , $C_L = 1$ μF		3.9		ms
	$V_{I(IN)} = 2.7$ V, $T_J = 25^\circ\text{C}$ , $C_L = 1$ μF		3.5		

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

**enable input ( $\overline{EN}$ )**

PARAMETER	TEST CONDITIONS	TPS2010, TPS2011 TPS2012, TPS2013			UNIT
		MIN	TYP	MAX	
High-level input voltage	$2.7 \text{ V} \leq V_{I(IN)} \leq 5.5 \text{ V}$	2			V
Low-level input voltage	$4.5 \text{ V} \leq V_{I(IN)} \leq 5.5 \text{ V}$			0.8	V
	$2.7 \text{ V} \leq V_{I(IN)} < 4.5 \text{ V}$			0.4	
Input current	$\overline{EN} = 0$ V or $\overline{EN} = V_{I(IN)}$	-0.5		0.5	μA
$t_{PLH}$ Propagation (delay) time, low-to-high-level output	$C_L = 1$ μF			20	ms
$t_{PHL}$ Propagation (delay) time, high-to-low-level output	$C_L = 1$ μF			40	

**current limit**

PARAMETER	TEST CONDITIONS†	TPS2010, TPS2011 TPS2012, TPS2013			UNIT	
		MIN	TYP	MAX		
Short-circuit current	$T_J = 25^\circ\text{C}$ , $V_{I(IN)} = 5.5$ V, OUT connected to GND, device enabled into short circuit	TPS2010	0.22	0.4	0.6	A
		TPS2011	0.66	1.2	1.8	
		TPS2012	1.1	2	3	
		TPS2013	1.65	2.6	4.5	

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

# TPS2010, TPS2011, TPS2012, TPS2013 POWER-DISTRIBUTION

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electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O = \text{rated current}$ ,  $\overline{EN} = 0\text{ V}$  (unless otherwise noted) (continued)

## supply current

PARAMETER	TEST CONDITIONS	TPS2010, TPS2011 TPS2012, TPS2013			UNIT
		MIN	TYP	MAX	
Supply current, low-level output	$\overline{EN} = V_{I(IN)}$	$T_J = 25^\circ\text{C}$	0.015	1	$\mu\text{A}$
		$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		10	
Supply current, high-level output	$\overline{EN} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	73	100	$\mu\text{A}$
		$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		100	

electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O = \text{rated current}$ ,  $\overline{EN} = 0\text{ V}$ ,  $T_J = 25^\circ\text{C}$  (unless otherwise noted)

## power switch

PARAMETER	TEST CONDITIONST	TPS2010Y, TPS2011Y TPS2012Y, TPS2013Y			UNIT
		MIN	TYP	MAX	
On-state resistance	$V_{I(IN)} = 5.5\text{ V}$ ,		75		$\text{m}\Omega$
	$V_{I(IN)} = 4.5\text{ V}$ ,		80		
	$V_{I(IN)} = 3\text{ V}$ ,		120		
	$V_{I(IN)} = 2.7\text{ V}$ ,		140		
Output leakage current	$\overline{EN} = V_{I(IN)}$		0.001		$\mu\text{A}$
Output rise time	$V_{I(IN)} = 5.5\text{ V}$ , $C_L = 1\text{ }\mu\text{F}$		4		ms
	$V_{I(IN)} = 2.7\text{ V}$ , $C_L = 1\text{ }\mu\text{F}$		3.8		
Output fall time	$V_{I(IN)} = 5.5\text{ V}$ , $C_L = 1\text{ }\mu\text{F}$		3.9		ms
	$V_{I(IN)} = 2.7\text{ V}$ , $C_L = 1\text{ }\mu\text{F}$		3.5		

T Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

## current limit

PARAMETER	TEST CONDITIONST	TPS2010Y, TPS2011Y TPS2012Y, TPS2013Y			UNIT
		MIN	TYP	MAX	
Short-circuit current	$V_{I(IN)} = 5.5\text{ V}$ , OUT connected to GND, Device enabled into short circuit		0.4		A

T Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

## supply current

PARAMETER	TEST CONDITIONS	TPS2010Y, TPS2011Y TPS2012Y, TPS2013Y			UNIT
		MIN	TYP	MAX	
Supply current, low-level output	$\overline{EN} = V_{I(IN)}$		0.015		$\mu\text{A}$
Supply current, high-level output	$\overline{EN} = 0\text{ V}$		73		$\mu\text{A}$



PARAMETER MEASUREMENT INFORMATION

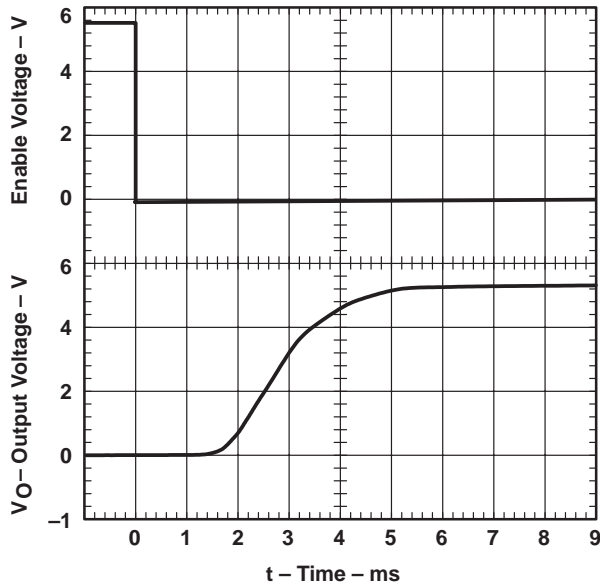


Figure 1. Propagation Delay and Rise Time With 1- $\mu$ F Load,  $V_{I(IN)} = 5.5$  V

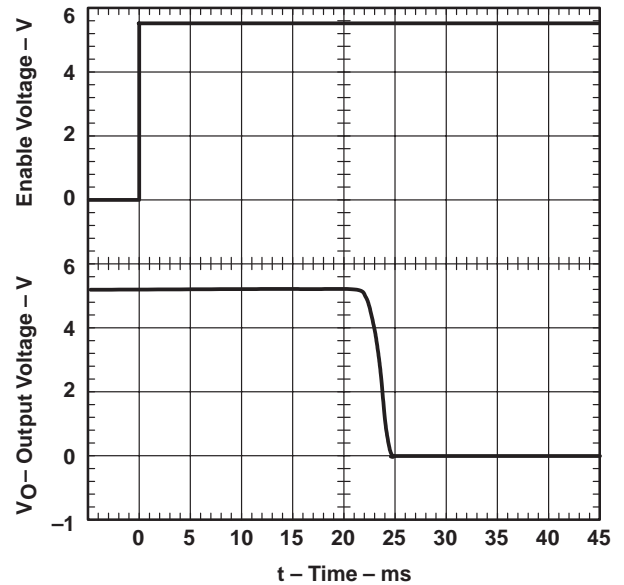


Figure 2. Propagation Delay and Fall Time With 1- $\mu$ F Load,  $V_{I(IN)} = 5.5$  V

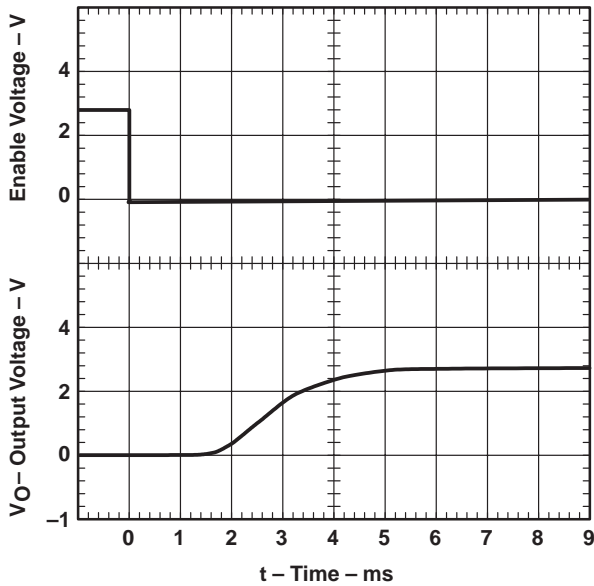


Figure 3. Propagation Delay and Rise Time With 1- $\mu$ F Load,  $V_{I(IN)} = 2.7$  V

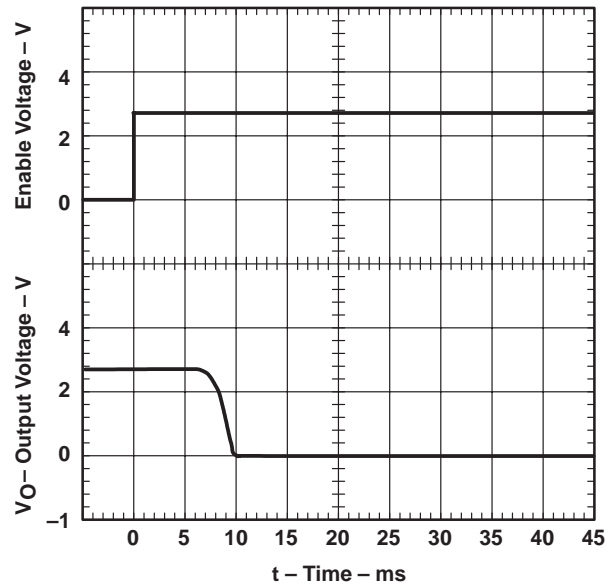


Figure 4. Propagation Delay and Fall Time With 1- $\mu$ F Load,  $V_{I(IN)} = 2.7$  V

PARAMETER MEASUREMENT INFORMATION

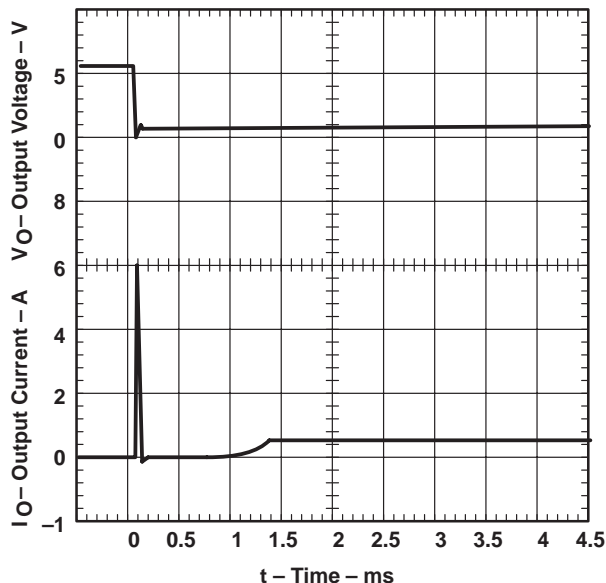


Figure 5. TPS2010, Short-Circuit Current.  
Short is Applied to Enabled Device,  $V_{I(IN)} = 5.5\text{ V}$

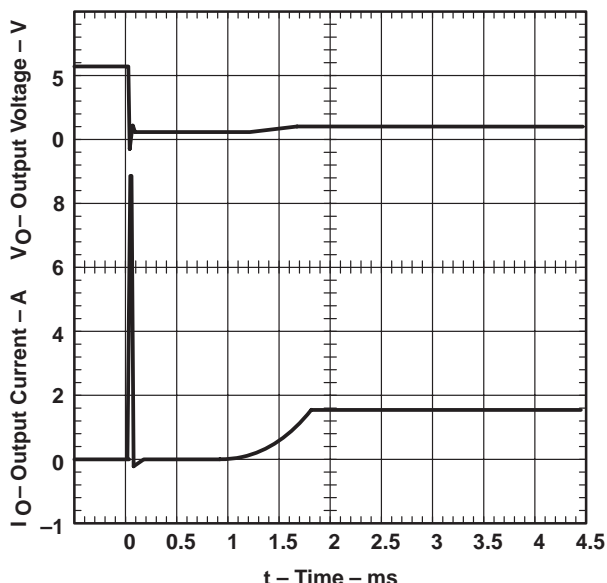


Figure 6. TPS2011, Short-Circuit Current.  
Short is Applied to Enabled Device,  $V_{I(IN)} = 5.5\text{ V}$

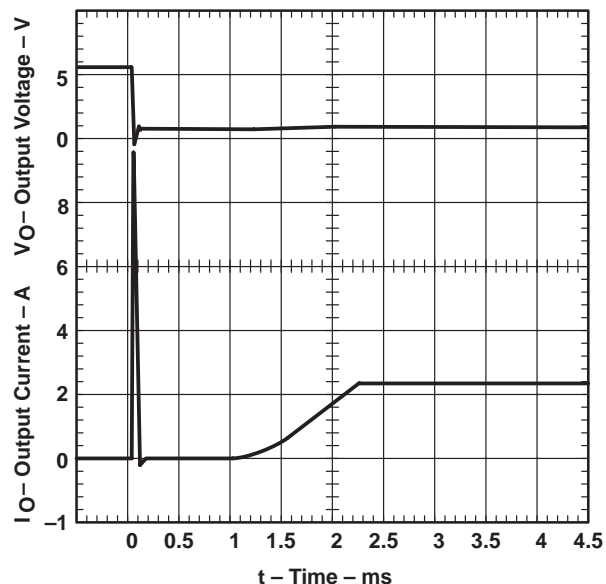


Figure 7. TPS2012, Short-Circuit Current.  
Short is Applied to Enabled Device,  $V_{I(IN)} = 5.5\text{ V}$

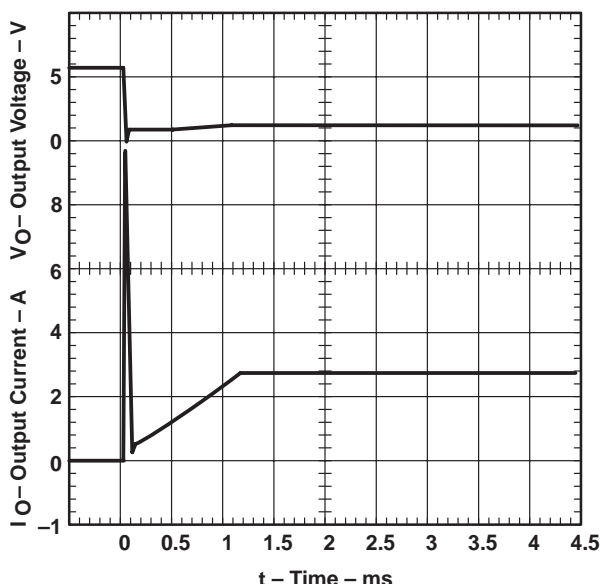


Figure 8. TPS2013 – Short-Circuit Current.  
Short is Applied to Enabled Device,  $V_{I(IN)} = 5.5\text{ V}$

PARAMETER MEASUREMENT INFORMATION

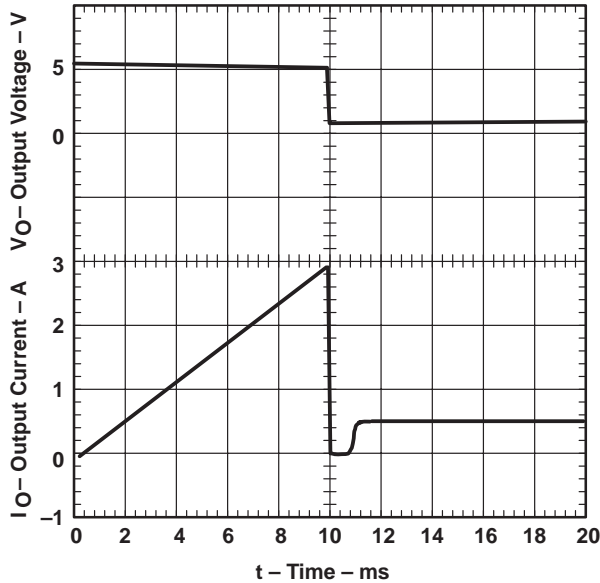


Figure 9. TPS2010 – Threshold Current,  
 $V_{I(IN)} = 5.5\text{ V}$

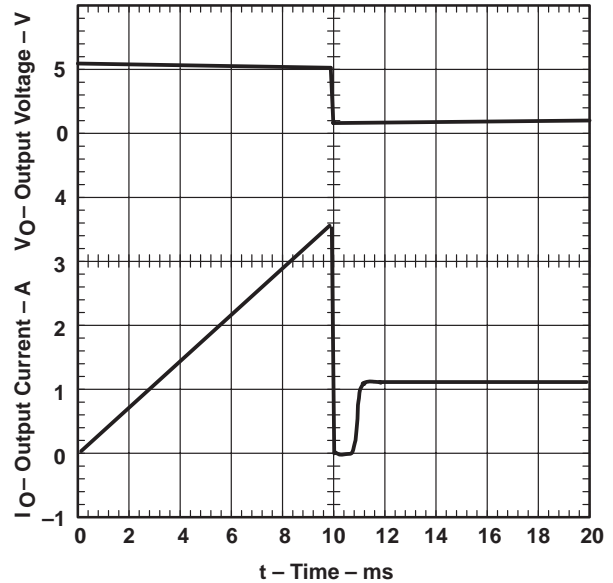


Figure 10. TPS2011 – Threshold Current,  
 $V_{I(IN)} = 5.5\text{ V}$

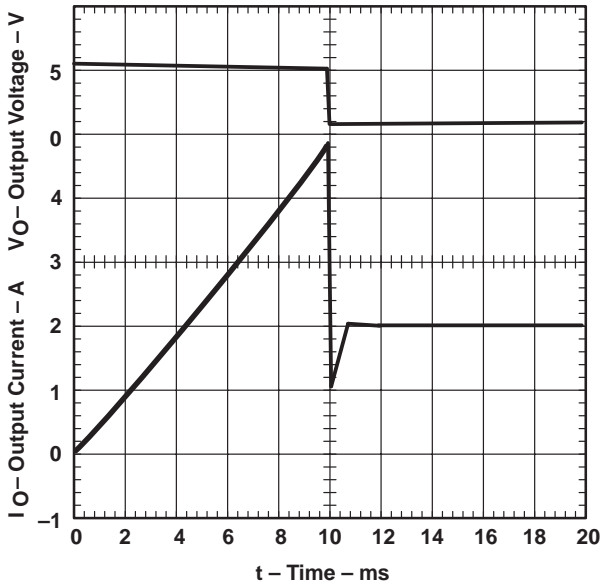


Figure 11. TPS2012 – Threshold Current,  
 $V_{I(IN)} = 5.5\text{ V}$

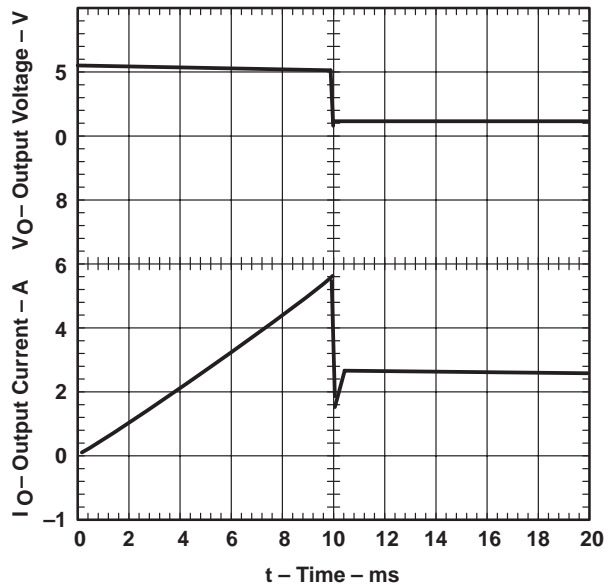


Figure 12. TPS2013 – Threshold Current,  
 $V_{I(IN)} = 5.5\text{ V}$

PARAMETER MEASUREMENT INFORMATION

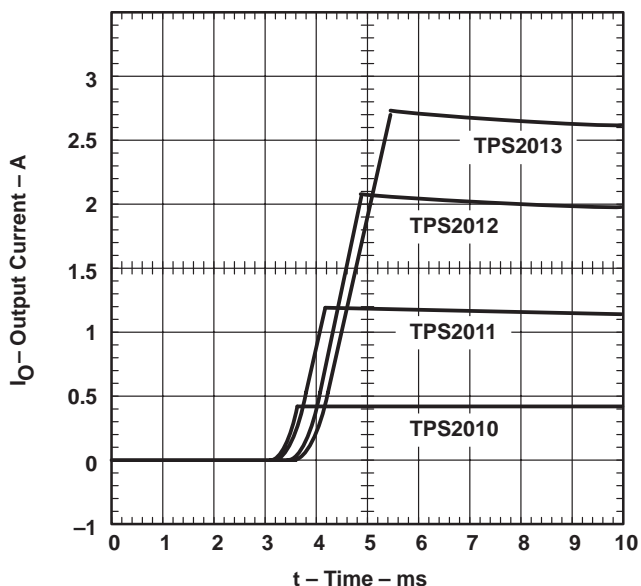


Figure 13. Turned-On (Enabled) Into Short Circuit,  $V_{I(IN)} = 5.5 V$

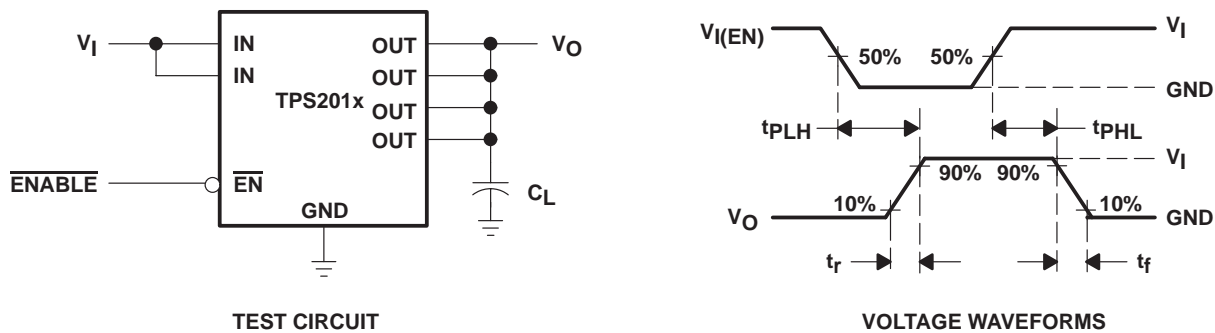


Figure 14. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

TURN-ON DELAY TIME  
vs  
INPUT VOLTAGE

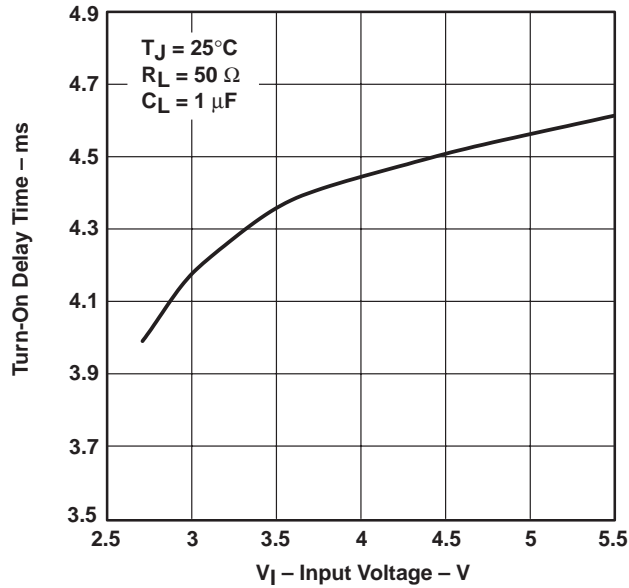


Figure 15

TURN-OFF DELAY TIME  
vs  
INPUT VOLTAGE

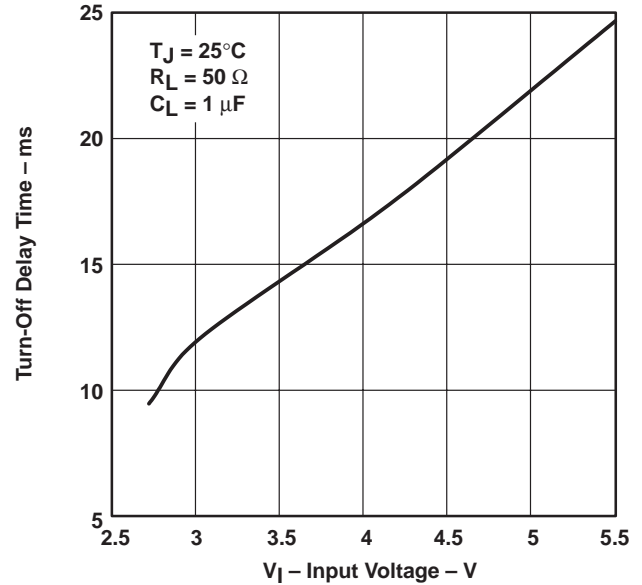


Figure 16

RISE TIME  
vs  
OUTPUT CURRENT

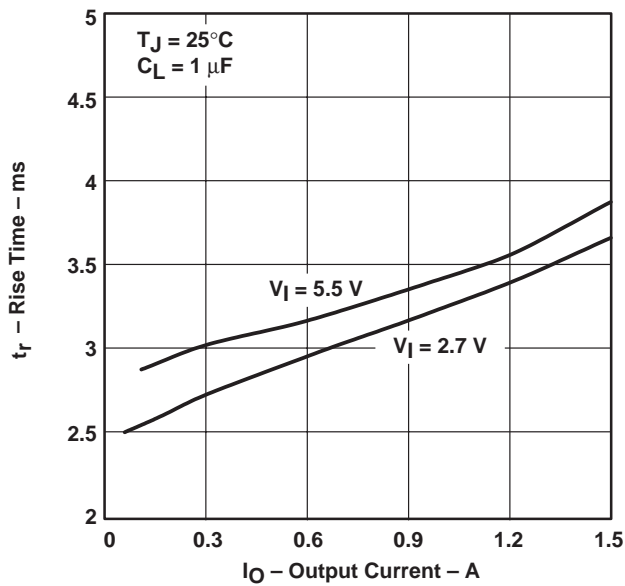


Figure 17

FALL TIME  
vs  
OUTPUT CURRENT

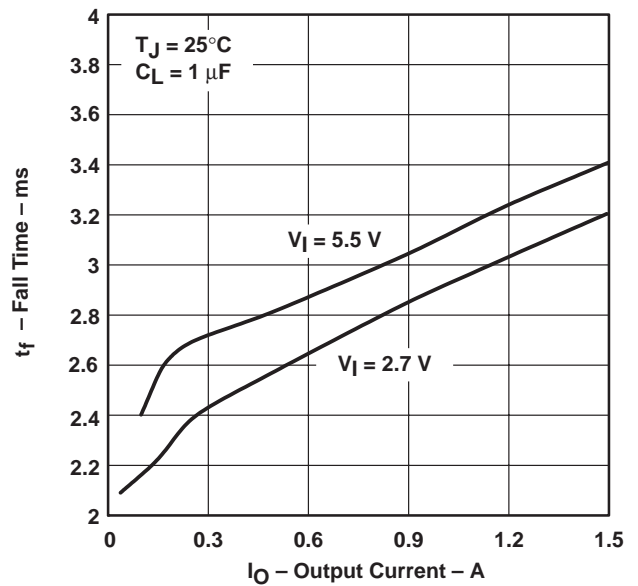


Figure 18

TYPICAL CHARACTERISTICS

SUPPLY CURRENT (OUTPUT ENABLED)  
vs  
JUNCTION TEMPERATURE

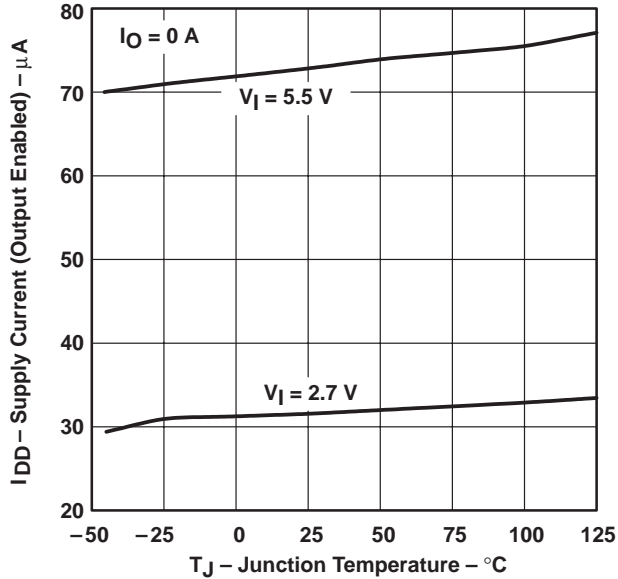


Figure 19

SUPPLY CURRENT (OUTPUT DISABLED)  
vs  
JUNCTION TEMPERATURE

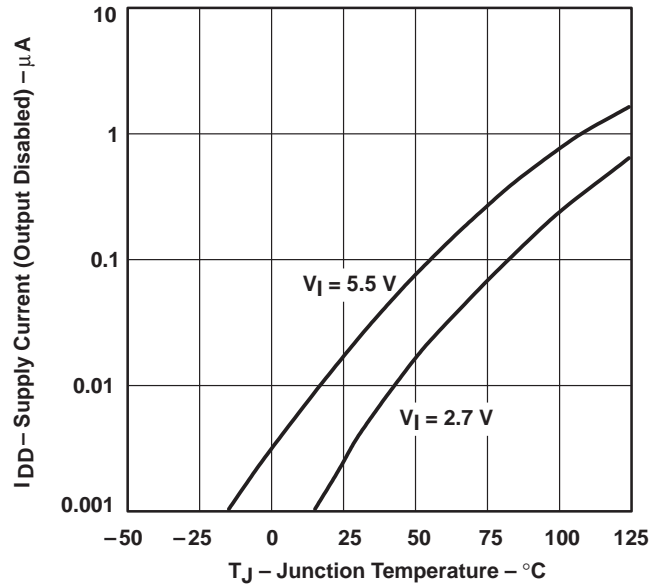


Figure 20

SUPPLY CURRENT (OUTPUT ENABLED)  
vs  
INPUT VOLTAGE

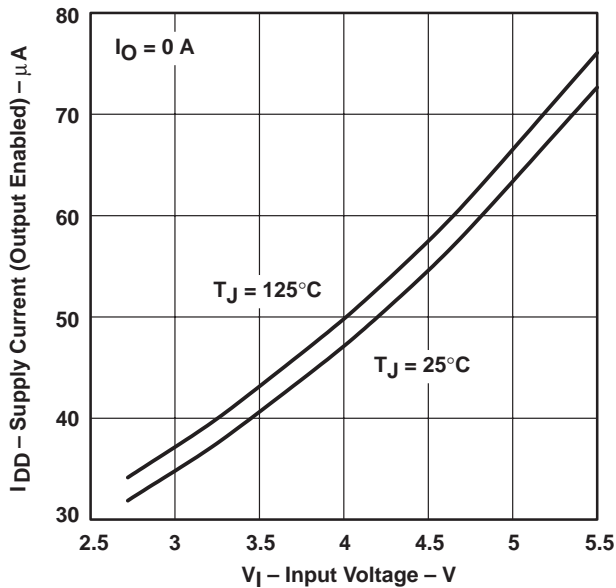


Figure 21

SUPPLY CURRENT (OUTPUT DISABLED)  
vs  
INPUT VOLTAGE

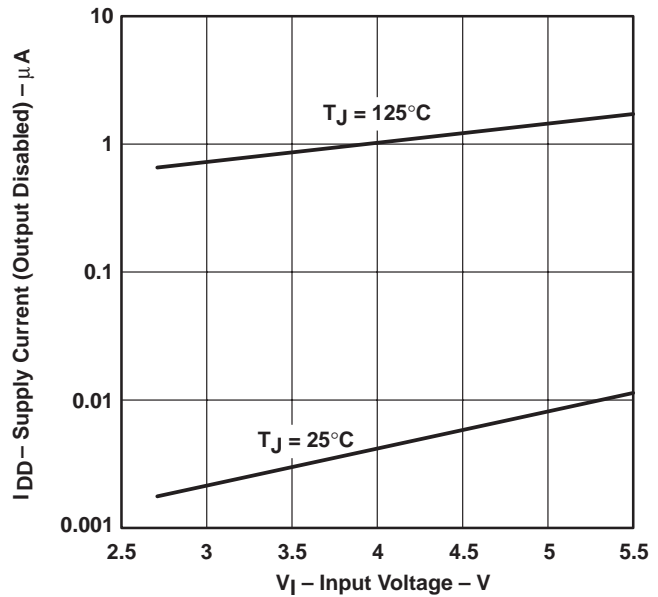


Figure 22

TYPICAL CHARACTERISTICS

ON-STATE RESISTANCE  
vs  
JUNCTION TEMPERATURE

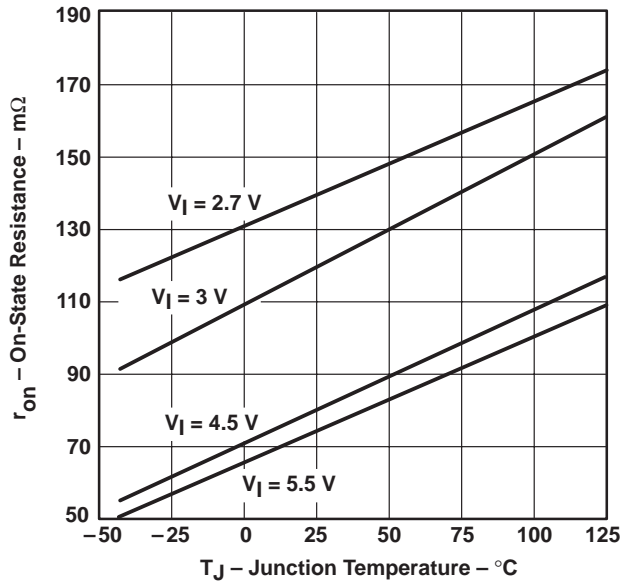


Figure 23

ON-STATE RESISTANCE  
vs  
INPUT VOLTAGE

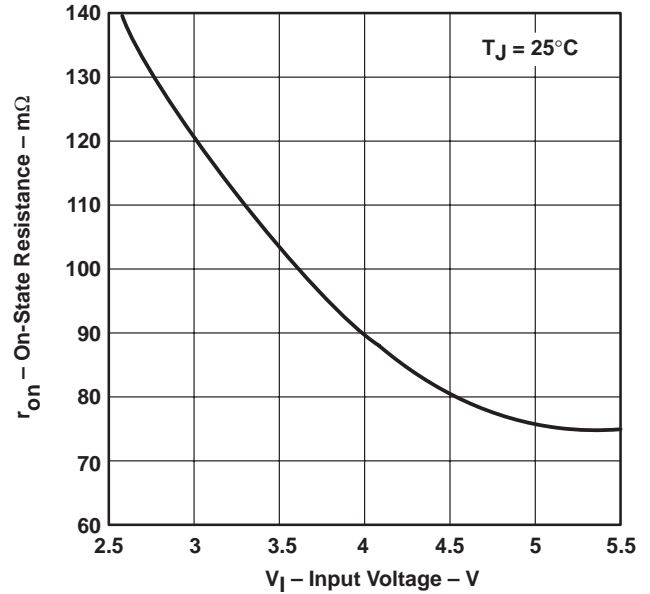


Figure 24

INPUT VOLTAGE TO OUTPUT VOLTAGE  
vs  
INPUT VOLTAGE

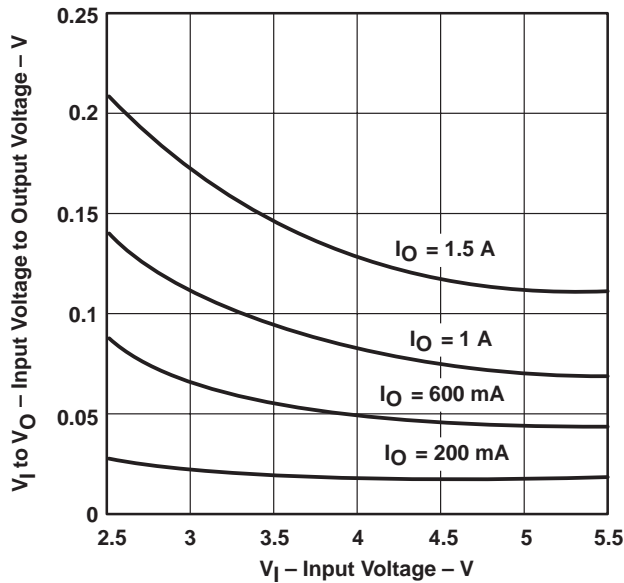


Figure 25

SHORT-CIRCUIT CURRENT  
vs  
INPUT VOLTAGE

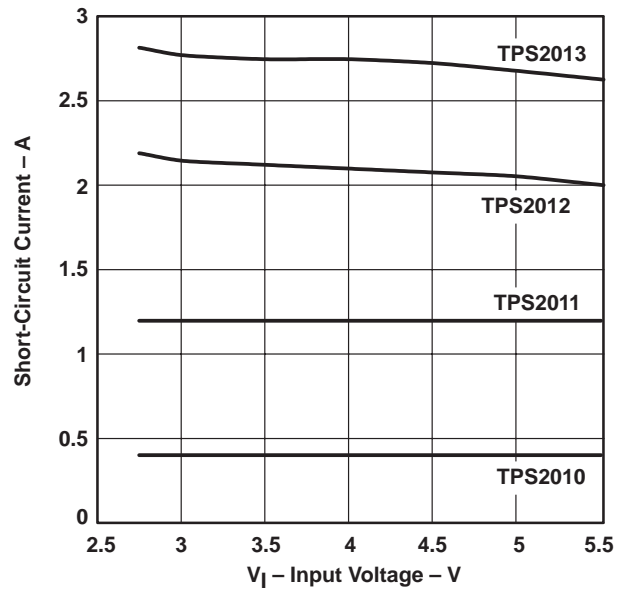


Figure 26

TYPICAL CHARACTERISTICS

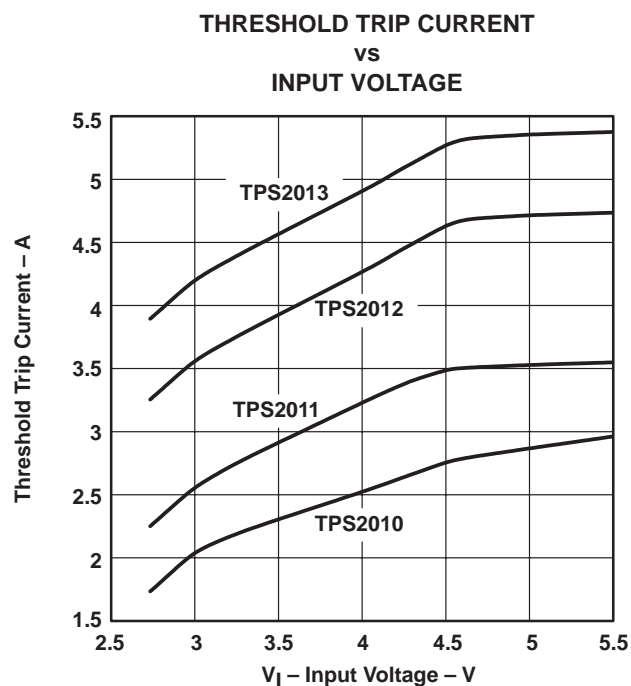


Figure 27

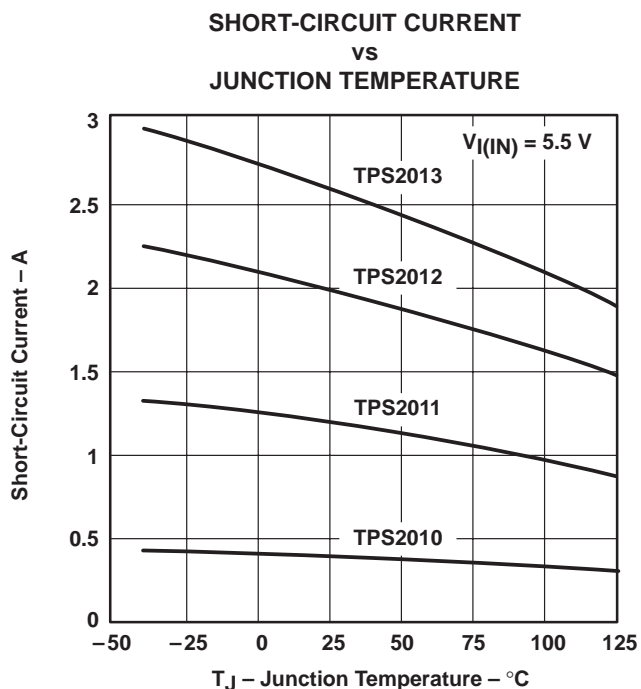


Figure 28

APPLICATION INFORMATION

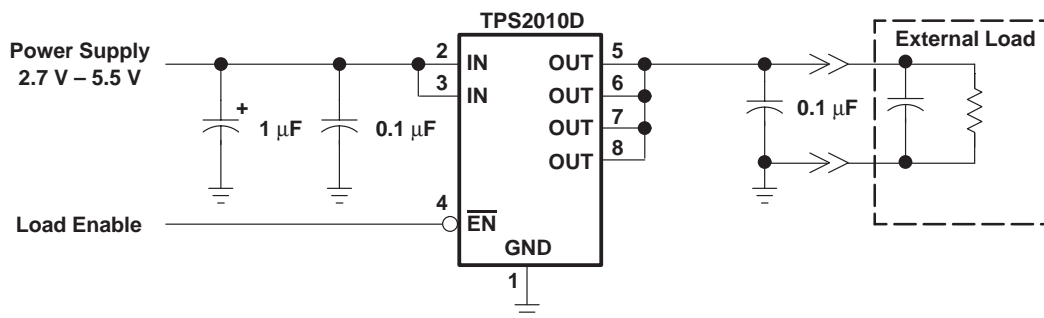


Figure 29. Typical Application

power supply considerations

The TPS201x family has multiple inputs and outputs, which must be connected in parallel to minimize voltage drop and prevent unnecessary power dissipation.

A 0.047-µF to 0.1-µF ceramic bypass capacitor between IN and GND, close to the device, is recommended. A high-value electrolytic capacitor is also desirable when the output load is heavy or has large paralleled capacitors. Bypassing the output with a 0.1-µF ceramic capacitor improves the immunity of the device to electrostatic discharge (ESD).

APPLICATION INFORMATION

overcurrent

A sense FET is employed to check for overcurrent conditions. Unlike sense resistors and polyfuses, sense FETs do not increase series resistance to the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Shutdown only occurs if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before  $V_{I(IN)}$  has been applied (see Figure 30). The TPS201x senses the short and immediately switches into a constant-current output.

Under the second condition, the short occurs while the device is enabled. At the instant the short occurs, very high currents flow for a short time before the current-limit circuit can react (see Figures 5, 6, 7, and 8). After the current-limit circuit has tripped, the device limits normally.

Under the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached (see Figures 9, 10, 11, and 12). The TPS201x family is capable of delivering currents up to the current-limit threshold without damage. Once the threshold has been reached, the device switches into its constant-current mode.

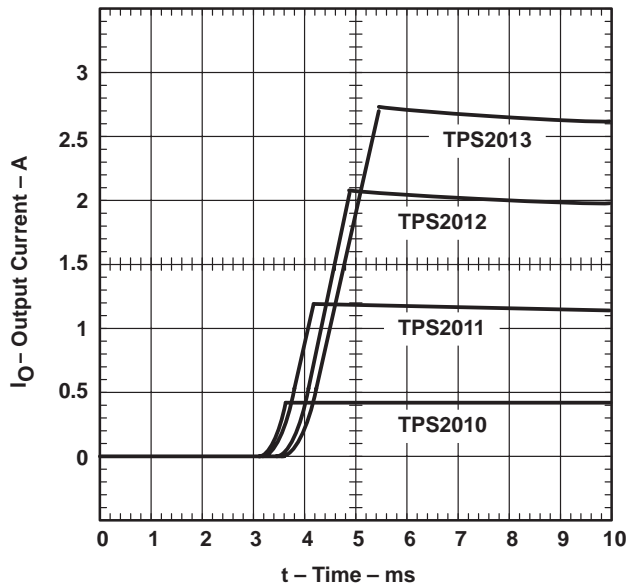


Figure 30. Turned-On (Enabled) Into Short Circuit,  $V_{I(IN)} = 5.5\text{ V}$

## APPLICATION INFORMATION

### power dissipation and junction temperature

The low on resistance of the N-channel MOSFET allows small surface-mount packages, such as SOIC or TSSOP to pass large currents. The thermal resistances of these packages are high compared to that of power packages; it is good design practice to check power dissipation and junction temperature. The first step is to find  $r_{on}$  at the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{on}$  from Figure 23. Next calculate the power dissipation using:

$$P_D = r_{on} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

$T_A$  = Ambient temperature

$R_{\theta JA}$  = Thermal resistance SOIC = 172°C/W, TSSOP = 179°C/W

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

### thermal protection

Thermal protection is provided to prevent damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The faults force the TPS201x into its constant current mode, which causes the voltage across the high-side switch to increase; under short-circuit conditions, the voltage across the switch is equal to the input voltage. The increased dissipation causes the junction temperature to rise to dangerously high levels. The protection circuit senses the junction temperature of the switch and shuts it off. The switch remains off until the junction has dropped approximately 20°C. The switch continues to cycle in this manner until the load fault or input power is removed.

### ESD protection

All TPS201x terminals incorporate ESD-protection circuitry designed to withstand a 6-kV human-body-model discharge as defined in MIL-STD-883C. Additionally, the output is protected from discharges up to 12 kV.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2010D	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2010	
TPS2010DR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2010	
TPS2010DRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2010	
TPS2011D	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2011	
TPS2011DR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2011	
TPS2011DRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2011	
TPS2012D	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2012	
TPS2012DR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2012	
TPS2013D	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2013	
TPS2013DR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2013	
TPS2013DRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2013	

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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- (3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2010DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2011DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2012DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2013DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2010DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2011DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2012DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2013DR	SOIC	D	8	2500	340.5	338.1	20.6

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